74AHC244; 74AHCT244

Octal buffer/line driver; 3-state

Rev. 05 — 20 December 2007

Product data sheet

1. General description

The 74AHC244; 74AHCT244 is a high-speed Si-gate CMOS device.

The 74AHC244; 74AHCT244 has octal non-inverting buffer/line drivers with 3-state outputs. The 3-state outputs are controlled by the output enable inputs (nOE). A HIGH on nOE causes the outputs to assume a high-impedance OFF-state.

2. Features

- Balanced propagation delays
- All inputs have a Schmitt-trigger action
- Inputs accepts voltages higher than V_{CC}
- For 74AHC244 only: operates with CMOS input levels
- For 74AHCT244 only: operates with TTL input levels
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

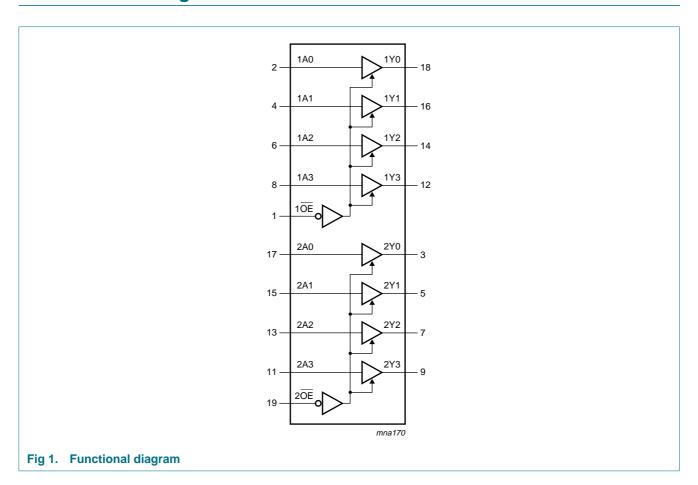
3. Ordering information

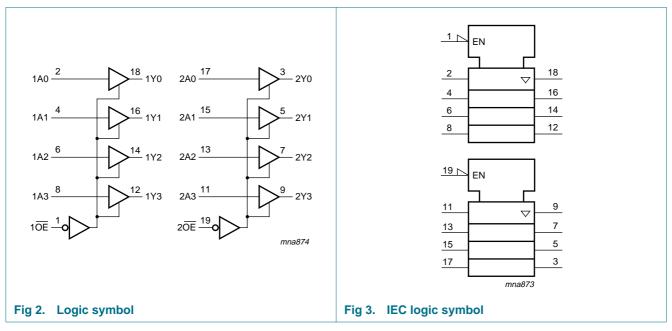
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AHC244D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1
74AHCT244D			body width 7.5 mm	
74AHC244PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1
74AHCT244PW			body width 4.4 mm	
74AHC244BQ	–40 °C to +125 °C	DHVQFN20	plastic dual-in-line compatible thermal enhanced	SOT764-1
74AHCT244BQ			very thin quad flat package; no leads; 20 terminals; body 2.5 \times 4.5 \times 0.85 mm	



4. Functional diagram

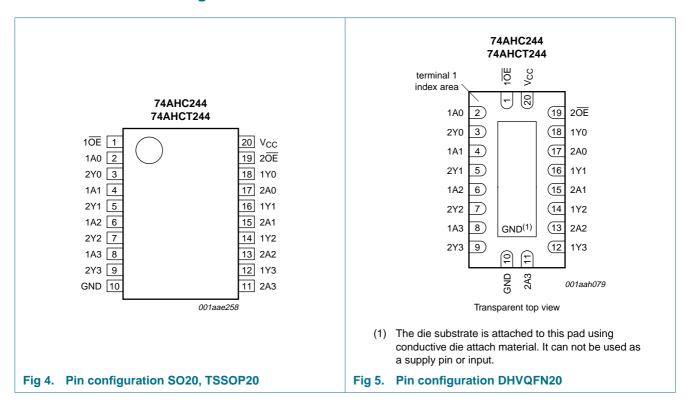




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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Table 2.	i ili description	
Symbol	Pin	Description
1 OE	1	output enable input (active LOW)
1A[0:3]	2, 4, 6, 8	data input
2A[0:3]	17, 15, 13, 11	data input
1Y[0:3]	18, 16, 14, 12	data output
2Y[0:3]	3, 5, 7, 9	data output
GND	10	ground (0 V)
2 OE	19	output enable input (active LOW)
V_{CC}	20	supply voltage

6. Functional description

Table 3. Function table [1]

Control	Input	Output
nŌĒ	nAn	nYn
L	L	L
	Н	Н
Н	X	Z

^[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		, ,			,
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 V$	<u>[1]</u> –20	-	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
I _O	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	75	mA
I_{GND}	ground current		–75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C}$ to +125 $^{\circ}\text{C}$			
	SO20 package		[2] _	500	mW
	TSSOP20 package		[3] _	500	mW
	DHVQFN20 package		<u>[4]</u> _	500	mW
	·	·			

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] P_{tot} derates linearly with 8 mW/K above 70 °C.

^[3] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

^[4] P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AHC	244		74AHC		Unit	
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise	V_{CC} = 3.3 V \pm 0.3 V	-	-	100	-	-	-	ns/V
a	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	–40 °C t	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
For type	74AHC244				'		•			
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = -50 \mu A$; $V_{CC} = 2.0 \text{ V}$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -50 \mu A$; $V_{CC} = 3.0 \text{ V}$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_O = -50 \mu A$; $V_{CC} = 4.5 \text{ V}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.70	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 50 \mu A$; $V_{CC} = 2.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A$; $V_{CC} = 3.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A$; $V_{CC} = 4.5 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}$; $V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}$; $V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $V_{CC} = 5.5 \text{ V}$	-	-	±0.25	-	±2.5	-	±10.0	μΑ
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	- 80		μΑ
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Table 6. Static characteristics ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	-40 °C t	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
C _I	input capacitance		-	3.0	10	-	10	-	10	pF
Co	output capacitance		-	4.0	-	-	-	-	-	pF
For type	74AHCT244									
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	-	0.8	-	0.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_{O} = -50 \mu\text{A}$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -8.0 \text{ mA}$	3.94	-	-	3.8	-	3.70	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
output voltage	Ι _Ο = 50 μΑ	-	0	0.1	-	0.1	-	0.1	V	
		$I_0 = 8.0 \text{ mA}$	-	-	0.36	-	0.44	-	0.55	V
l _{OZ}	OFF-state output current	per input pin; $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5 \text{ V}$; $I_O = 0 \text{ A}$	-	-	±0.25	-	±2.5	-	±10.0	μΑ
		$V_O = V_{CC}$ or GND; other pins at V_{CC} or GND								
II	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μΑ
ΔI_{CC}	additional supply current	per input pin; $V_{I} = V_{CC} - 2.1 \text{ V; } I_{O} = 0 \text{ A;}$ other pins at V_{CC} or GND; $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	1.35	-	1.5	-	1.5	mA
C _I	input capacitance		-	3	10	-	10	-	10	pF
Co	output capacitance		-	4.0	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics *GND* = 0 *V. For test circuit see Figure 8.*

Symbol	Parameter	Conditions			25 °C		-40 °C 1	to +85 °C	-40 °C 1	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
For type	74AHC244								'		
t _{pd}	propagation	nAn to nYn; see Figure 6	[2]								
	delay	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$									
		$C_L = 15 pF$		-	5.0	8.4	1.0	10.0	1.0	10.5	ns
		$C_L = 50 pF$		-	7.0	11.9	1.0	13.5	1.0	15.0	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 pF$		-	3.4	5.5	1.0	6.5	1.0	7.0	ns
		$C_L = 50 pF$			5.0	7.5	1.0	8.5	1.0	9.5	ns
t _{en}	enable time	nOE to nYn; see Figure 7	[2]								
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$									
		$C_L = 15 pF$		-	6.5	10.6	1.0	12.5	1.0	13.5	ns
		$C_L = 50 pF$		-	7.5	14.1	1.0	16.0	1.0	18.0	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 pF$		-	4.0	7.3	1.0	8.5	1.0	9.5	ns
		$C_L = 50 pF$		-	5.5	9.3	1.0	10.5	1.0	12.0	ns
t _{dis}	disable time	nOE to nYn; see Figure 7	[2]								
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$									
		$C_L = 15 pF$		-	5.5	9.7	1.0	11.0	1.0	12.5	ns
		$C_L = 50 pF$		-	10.0	14.0	1.0	16.0	1.0	17.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 pF$		-	4.8	7.2	1.0	8.5	1.0	9.0	ns
		$C_L = 50 pF$		-	7.0	9.2	1.0	10.5	1.0	11.5	ns
C_{PD}	power dissipation capacitance	C_L = 50 pF; f_i = 1 MHz; V_I = GND to V_{CC}	[3]	-	10	-	-	-	-	-	pF

Dynamic characteristics ...continued Table 7. GND = 0 V. For test circuit see Figure 8.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C t	Unit	
				Min	Typ[1]	Max	Min	Max	Min	Max	
For type	74AHCT244							ı	1		
t _{pd}	propagation	nAn to nYn; see Figure 6	[2]								
	delay	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C _L = 15 pF		-	3.5	7.4	1.0	8.5	1.0	9.5	ns
		$C_{L} = 50 \text{ pF}$		-	5.0	8.4	1.0	9.5	1.0	10.5	ns
t _{en}	enable time	nOE to nYn; see Figure 7									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C _L = 15 pF		-	3.5	10.4	1.0	12.0	1.0	13.0	ns
		$C_{L} = 50 \text{ pF}$		-	5.5	11.4	1.0	13.0	1.0	14.5	ns
t _{dis}	disable time	nOE to nYn; see Figure 7	[2]								
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C _L = 15 pF		-	5.0	9.4	1.0	10.0	1.0	12.0	ns
		$C_L = 50 pF$		-	7.0	11.4	1.0	13.0	1.0	14.5	ns
C_{PD}	power dissipation capacitance	per buffer; C _L = 50 pF; f = 1 MHz; V _I = GND to V _{CC}	[3]	-	12	-	-	-	-	-	pF

- [1] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$ and $V_{CC} = 5.0 \text{ V}$).
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .

t_{en} is the same as t_{PZL} and t_{PZH}.

t_{dis} is the same as t_{PLZ} and t_{PHZ}.

[3] C_{PD} is used to determine the dynamic power dissipation P_D (μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

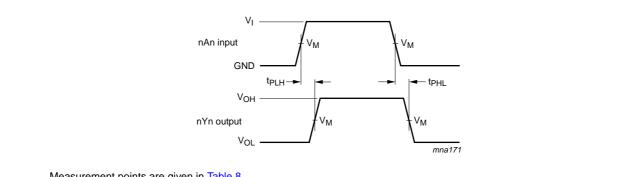
f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts.

11. Waveforms



Measurement points are given in Table 8.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 6. Propagation delay input (nAn) to output (nYn)

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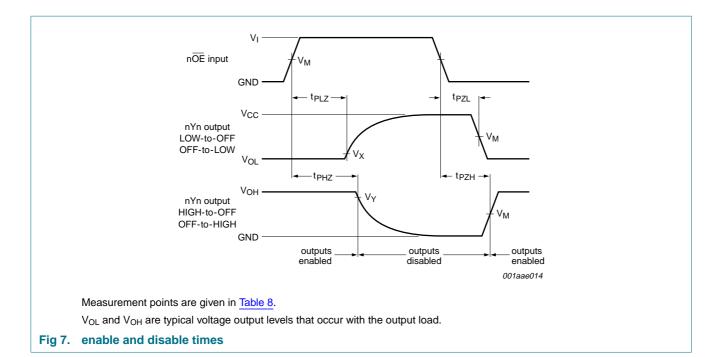
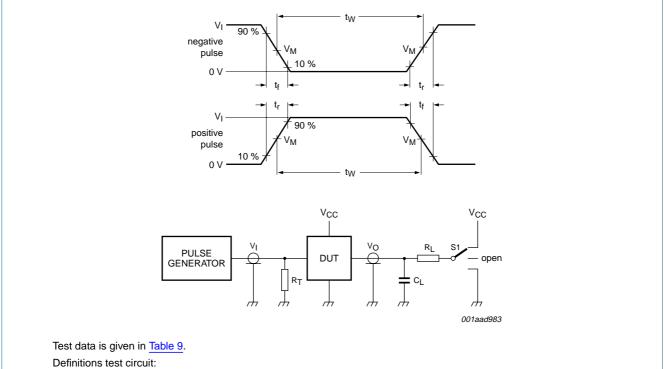


Table 8. Measurement points

Туре	Input	Output							
	V _M	V _M	V _X	V _Y					
74AHC244	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V					
74AHCT244	1.5 V	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V					



 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator

C_L = Load capacitance including jig and probe capacitance

R_L = Load resistor

S1 = Test selection switch

Fig 8. Load circuitry for switching times

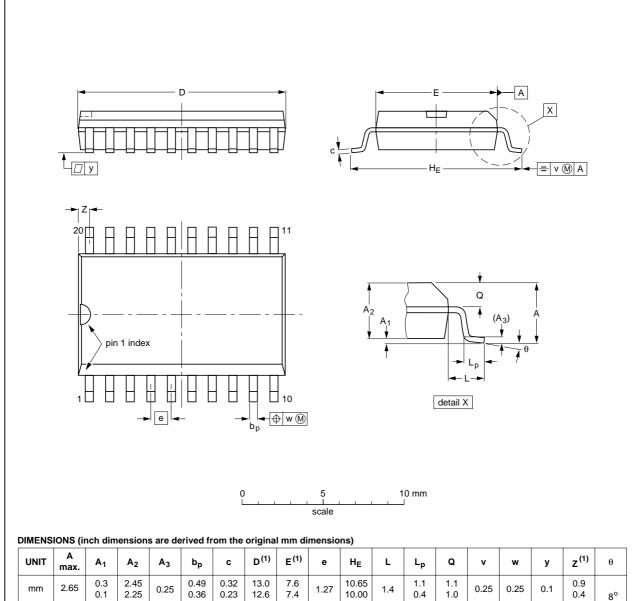
Table 9. **Test data**

Туре	Input		Load		S1 position	S1 position				
	VI	t _r , t _f	CL	R_L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}			
74AHC244	V_{CC}	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V_{CC}			
74AHCT244	3.0 V	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V_{CC}			

12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014		0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016		0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

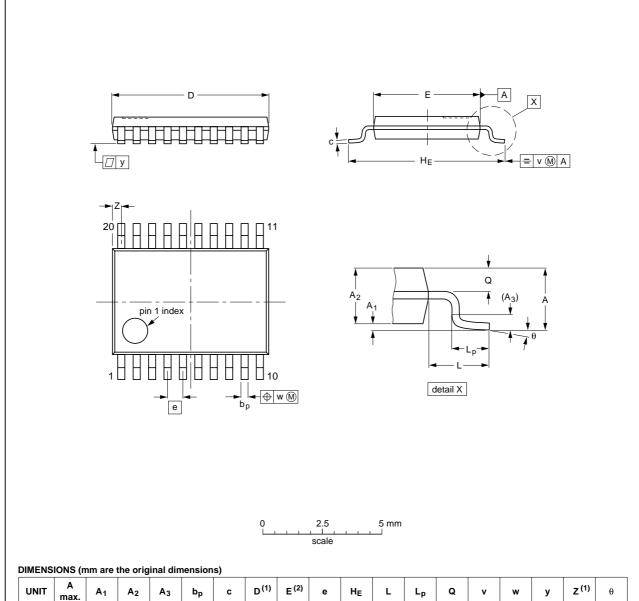
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013				99-12-27 03-02-19	

Fig 9. Package outline SOT163-1 (SO20)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



_							٠-,												
	UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
	mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT360-1		MO-153				99-12-27 03-02-19

Fig 10. Package outline SOT360-1 (TSSOP20)

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

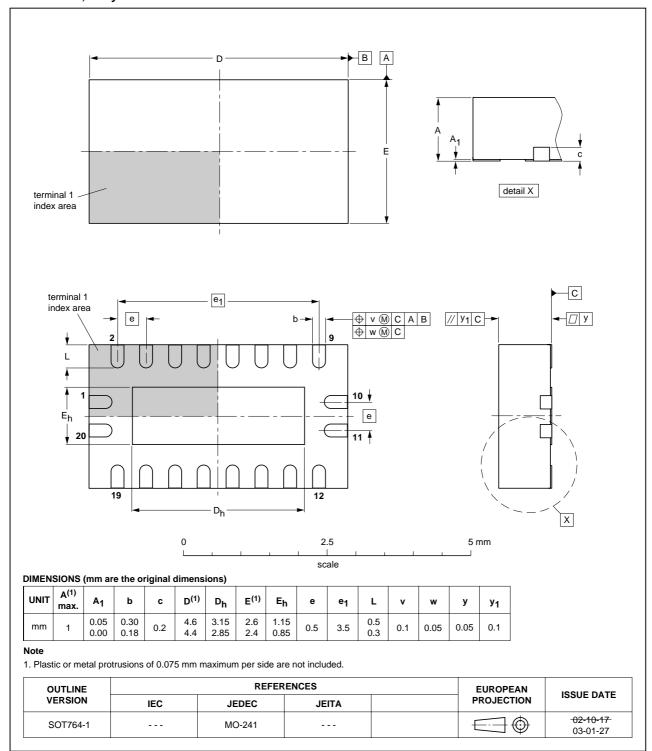


Fig 11. Package outline SOT764-1 (DHVQFN20)

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charge Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT244_5	20071220	Product data sheet	-	74AHC_AHCT244_4
Modifications:		of this data sheet has beer of NXP Semiconductors.	redesigned to comply	with the new identity
	 Legal texts 	have been adapted to the r	new company name wl	here appropriate.
	• Section 3: E	HVQFN20 package added	d.	
	• Section 7: d	erating values added for D	HVQFN20 package.	
	• Section 12:	outline drawing added for I	DHVQFN20 package.	
74AHC_AHCT244_4	20060210	Product data sheet	-	74AHC_AHCT244_3
74AHC_AHCT244_3	19990928	Product specification	-	74AHC_AHCT244_2
74AHC_AHCT244_2	19990224	Product specification	-	74AHC_AHCT244_1
74AHC AHCT244 1	19980921	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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